WELLCOMP TECHNOLOGY CO., LTD

APPROVAL SHEET

Model Name	Metal Strip Current Sensing Resistor -High Power
Part Number	WMCSH2512 Series
Customer Name	
Customer P/N	
Issued Date	

Customer		Maker		
Approved	Checked	Inspector	Prepared	



元璽科技股份有限公司

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Metal Strip Current Sensing Resistor-High Power

Document No: 20130305002 Issued Date: 2013/03/05

Version: A02

Features

- ◆Able to withstand high temperature and high current
- ◆Ultra Low sensing resistance
- ◆Excellent frequency response
- ♦Chip size: 2512
- Lead free, RoHS compliant for global applications and halogen free

Application

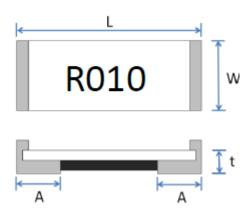
- ◆Mobile electronic equipment-Cellular phone, NB Tablet PC, GPS, DSC, HDD
- ◆DC-DC converter, Adapter, Battery pack and charger
- ◆Switching power supply
- ◆Voltage Regulation module
- ◆Power management applications

Part Numbering System

<u>WMCSH 2512 R050 F H E A</u>

- (1) (2) (3) (4) (5) (6) (7)
- (1) Series Code
- (2) Size (EIA): Length x Width
- (3) Resistance: R002=2m Ω , R010=10m Ω
- (4) Tolerance: F=+/-1%, G=+/-2%, J=+/-5%
- (5) Power Rating: S=1/2W, C=1W, D=1.5W, E=2W, H=3W
- (6) Packaging: E-Embossed plastic tape, 7" reel
- (7) Factory Code, A=TWN Factory

Dimension



Туре		nsions(mm)		
(inch size)	L	W	t	Α
WMCSH2512	6.45±0.20	3.25±0.20	0.80±0.15	1.10±0.25



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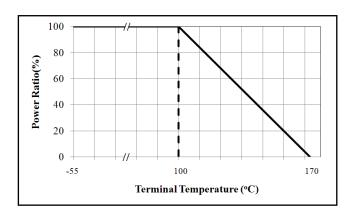
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Electrical Specification

Item	Power Rating	Resistance Range(m Ω)	Operation Temp. Range	TCR (PPM/°C)
WMCSH2512	214/	10 <u><</u> R <u><</u> 600	FF0::470°C	±50
	3W	4 <u><</u> R<10	-55~+170°C	±100

Derating Curve



Performances

Environmental Performance

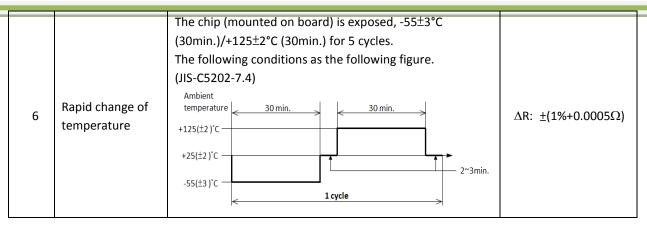
No.	Item	Test Condition	Specification
1	Short Time Overload	Loading 3 time rated power for 5 sec , (JIS-C5202-5.5)	Δ R: ±(1%+0.0005Ω)
2	Temperature Coefficient of Resistance (T.C.R.)	+25°C /+125°C. (JIS-C5202-5.2) $TCR \text{ (ppm/°C)} = \frac{\Delta R}{R \times \Delta t} \times 10^{6}$	Refer to Electrical Specification
3	Damp Heat with Load	The specimens shall be placed in a chamber and subjected to a relative humidity of 90~95% percent and a temperature of 40° ±2°C for the period of 1000 hrs. (MIL-STD-202, Method 103)	Δ R: ±(1%+0.0005Ω)
4	High Temperature Exposure	The ship (mounted on board) is exposed in the heat chamber 125 \pm 3 $^{\circ}$ C for 1000 hrs. (JIS-C5202-7.2)	Δ R: ±(1%+0.0005Ω)
5	Load Life	Apply rated power at 70±2°C for 1000 hours with 1.5 hours ON and 0.5 hour OFF. (JIS-C5202-7.10)	ΔR: ±(1%+0.0005Ω)



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Function Performance

No.	ltem	Test Condition	Specification
1	Bending Strength	Mount the chip to test substrate. Apply pressure in direction of arrow unit band width reaches 2mm(+0.2/-0mm) illustrated in the figure below and hold for 10±1 sec. (JIS-C5202-6.1) Unit: mm Position before bend Testing printed circuit board	Δ R: ±(1%+0.0005 Ω)
5	Solvent Resistance	The chip is completed immersion of the specimens in the isopropyl alcohol for 3 *+5, -0) min., 25°C ±5°C. ((MIL-STD-202, Method 215)	Verify marking permanency. (Nor required for laser etched parts or parts with no marking)
6	Resistance to solder Heat	The specimen chip shall be immersed into the flux specified in the solder bath $260\pm5^{\circ}$ C for 10 ± 1 sec. (MIL-STD-202, Method 210)	Δ R: ±(1%+0.0005Ω)
7	Solderability	The specimen chip shall be immersed into the flux specified in the solder bath $235\pm5^{\circ}\mathbb{C}$ for 2 ± 0.5 sec. It shall be immersed to a point 10mm from its root. (Sn96.5/Ag3.0/Cu0.5) (JIS-C5 202-6.11) Molten solder Specimen SNID $h = 10 \text{ mm}$ $H = 10 \text{ mm}$ min.	Solder shall be covered 95% or more of the electrode area.



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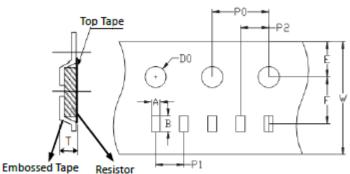
Version: A02

Remark:

a. 3 W with total solder pad trace size of 300 mm². The surface temperature of component should below 100° C.

Tape Packaging Specifications

◆Paper Tape Specifications



Unit:mm

Туре	Carrier Dimensions									
Турс	Α	В	E	F	W	P0	P1	P2	D0	T
2512	3.5±0.1	6.8±0.1	1.75±0.1	5.5±0.05	12.0±0.2	4.0±0.05	4.0±0.1	2.0±0.05	1.5±0.1	1.0±0.2

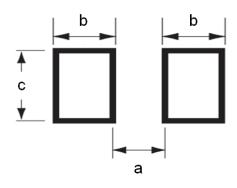
Packaging

Size EIA (EIAJ)	2512
Standard Packing Quantity (pcs /reel)	4,000

Storage Conditions

Temperature : $5^{\circ}35^{\circ}C$, Humidity : $40^{\circ}75\%$

Recommended Solder Pad Layout



Turno	Pad Layout Dimension (mm)					
Type	a b		С			
2512	3.80	2.10	3.40			



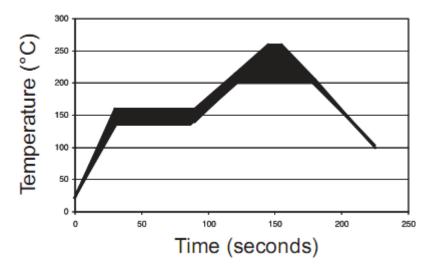
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Soldering Recommendations

- ◆ Peak reflow temperatures and durations:
 - IR Reflow Peak = 260° C max for 10 sec
 - Wave Solder = 260°C max for 10 sec
- ◆ Compatible with lead and lead-free solder reflow processes
- ◆ Recommended IR Reflow Profile:



ECN

Engineering Change Notice: The customer will be informed with ECN if there is significant modification on the characteristics and materials described in Approval Sheet.

单击下面可查看定价,库存,交付和生命周期等信息

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